UTG70N65FQ-S

Preliminary

Insulated Gate Bipolar Transistor

650V TRENCH GATE FIELD-STOP IGBT

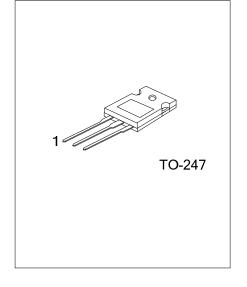
■ DESCRIPTION

The UTC **UTG70N65FQ-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

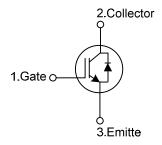
The UTC ${\it UTG70N65FQ-S}$ is suitable for the resonant or soft switching applications.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT).Typ.}$ =1.65V @ I_C=70A, V_{GE} =15V (T_C =25°C)



■ SYMBOL



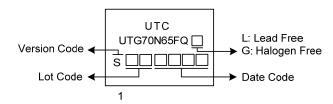
ORDERING INFORMATION

Ordering Number		Daakana	Pin Assignment			Da alsina	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG70N65FQL-S-T47-T	UTG70N65FQG-S-T47-T	TO-247	G	C	Е	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UTG70N65FQG-S-T47-T (1)Packing Type (2) T47: T0-247
(3)Version Code (3) Version S
(4)Green Package (4) G: Halogen Free and Lead Free, L: Lead Free

■ MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V _{CES}	650	V	
Gate-Emitter Voltage		V	±20	V	
Transient Gate-emitter voltage (tp < 5 ms)		V_{GES}	±25	V	
Cantinuous Callastan Cumant	T _C =25°C		140	Α	
Continuous Collector Current	T _C =100°C	Ic	70	Α	
Collector Current Pulsed (Note 1)		Ісм	280	Α	
Diada Famurand Cumant	T _C =25°C	I _F	84	Α	
Diode Forward Current	T _C =100°C		42	Α	
Short Circuit Withstand Time V _{GE} = 15V, V _{CC} ≤ 200V		tsc			
Allowed number of short circuits < 1000			5	μs	
Time between short circuits: ≥1.0s					
T _{VJ} = 25°C					
Power Dissipation (T _C =25°C)		P _D	285	W	
Operating Junction Temperature		T_J	-40 ~ +150	°C	
Storage Temperature Range		T _{STG}	-55 ~ + 150	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	0.10	0.44	°C/W

^{2.} Pulse width limited by maximum junction temperature.

■ ELECTRICAL CHARACTERISTICS (Tc=25°C, unless otherwise noted)

PARAMETER	PARAMETER SYMBOL		MIN	TYP	MAX	UNIT
Off Characteristics						
Collector-Emitter Breakdown Voltage	BV _{CES}		650			V
Collector Cut-Off Current	I _{CES}	V _{CE} =650V, V _{GE} =0V			5	μA
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			±400	nA
On Characteristics						
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	I _C =250μA, V _{CE} =V _{GE}	4.5		7.5	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =70A, V _{GE} =15V		1.65	2.1	V
Collector to Enritter Saturation Voltage	V CE(SAT)	T _C =125°C		2.0		V
Dynamic Characteristics						
Input Capacitance	C _{IES}			2900		pF
Output Capacitance	Coes	V _{CE} =25V, V _{GE} =0V, f=1MHz		224		pF
Reverse Transfer Capacitance	C _{RES}			44		pF
Switching Characteristics						
Total Gate Charge	Q_{G}			152		nC
Gate-Emitter Charge	Q_GE	V _{CE} =520V, I _C =70A, V _{GE} =15V		69		nC
Gate-Collector Charge	Q_{GC}			55		nC
Turn-On Delay Time	t _{DON)}			33		ns
Rise Time	t _R			103		ns
Turn-Off Delay Time	t _{DOFF)}	V_{CC} =400V, I_{C} =70A, R_{G} =10 Ω ,		115		ns
Fall Time	t _F	V _{GE} =0~15V, L=1000uH		52		ns
Turn-On Switching Loss	Eon			3.42		mJ
Turn-Off Switching Loss	E _{OFF}			2.13		mJ
SOURCE- DRAIN DIODE RATINGS AND	CHARACTE	RISTICS	•	•	•	
Forward Voltage Drop	VF	I _F =70A			3.0	V
Reverse Recovery Time	t _{rr}	I _F =70A, dI/dt=100A/µS, V _{CC} =400V		213		ns
Reverse Recovery Charge	Qrr			4.1		μC
		-		_		

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